

UV / Visible Sensor

GVGR-S11SD

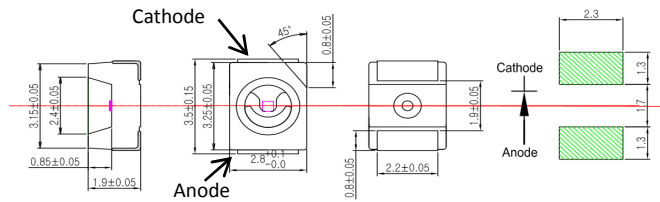


- Features**
- SMD3528 with Si-encapsulant
 - Indium Gallium Nitride Based Material
 - PN-type Photodiode
 - Photovoltaic Mode Operation
 - High Responsivity & Low Dark Current



- Applications**
- UV LED Monitoring (385, 405nm, etc.)
 - Blue LED Monitoring
 - UVA Lamp Monitoring
 - UV Curing

Outline Diagrams and Dimensions



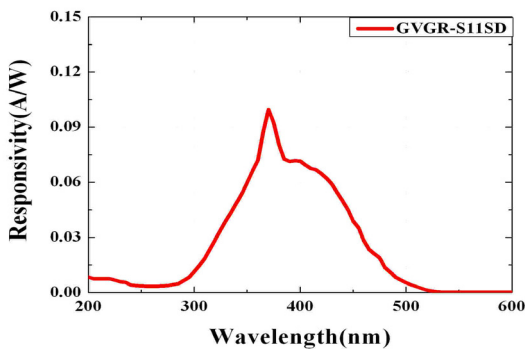
Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Remark
Storage Temperature	T _{st}	-40	90	°C	
Operating Temperature	T _{op}	-30	85	°C	
Reverse Voltage	V _{r, max.}		5	V	
Forward Current	I _{f, max.}		1	mA	
Soldering Temperature	T _{sol}		260	°C	within 10 sec.

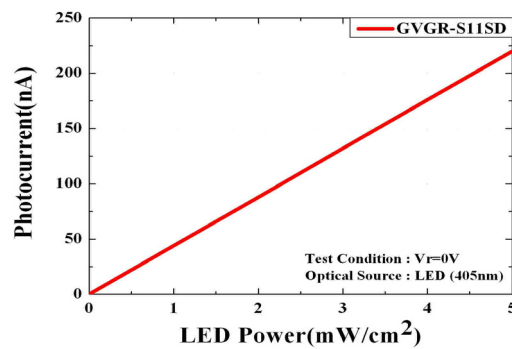
Characteristics (at 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Dark Current	I _d			1	nA	V _r = 0.1 V
Photo Current	I _{ph}		44		nA	LED (405nm), 1mW/cm ²
Responsivity	R		0.07		A/W	λ = 405 nm, V _r = 0 V
Spectral Detection Range	λ	295		490	nm	10% of R

Responsivity Curve



Photocurrent along LED Power



Caution

ESD can damage the device hence please avoid ESD.